WEST Search History



DATE: Friday, September 02, 2005

| Hide? | Set Name | e Query | Hit Count |
|--------------------------------|----------|--|-----------|
| DB=EPAB,JPAB; PLUR=YES; OP=ADJ | | | |
| Γ | L17 | L15 and shar\$ adj4 capacitor | 10 |
| Γ | L16 | L15 and shar\$ adj3 coupl\$ adj4 capacitor | 0 |
| Γ | L15 | memory and cell | 33042 |
| | DB=PG | PB, USPT; PLUR=YES; OP=ADJ | |
| Γ | L14 | L13 and shar\$ adj3 coupl\$ adj4 capacitor | 4 |
| Γ | L13 | memory and cell | 200558 |
| Γ | L12 | L11 and (electrode\$ or terminal\$) | 81 |
| Г | L11 | L5 and coupl\$ adj5 capacitor\$ | 119 |
| Γ | L10 | L5 and shar\$ adj5 capacitor\$ | 5 |
| Г | L9 | L8 and shar\$ adj5 capacitor\$ | 3 |
| Γ | L8 | L7 and word\$ and bit\$ | 199 |
| Γ | L7 | L6 and substrate\$ | 280 |
| Γ | L6. | L5 and electrode | 288 |
| Г | L5 | L4 and source\$ and drain\$ | 441 |
| Γ | L4 | L3 and (floating-gate or floating gate) | 467 |
| Г | L3 | L2 and MOS\$ adj2 capacitor | 918 |
| Γ | L2 | L1 and (nonvolatile or non-volatile) | 39899 |
| Г | L1 | memory and cell | 200558 |

END OF SEARCH HISTORY